

**BAT54CV** Two Schottky barrier double diodes Rev. 3 – 15 November 2010

**Product data sheet** 

# 1. Product profile

#### 1.1 General description

Two planar Schottky barrier double diodes with common cathodes and an integrated guard ring for stress protection encapsulated in a SOT666 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

#### **1.2 Features and benefits**

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified
- Ultra small and flat lead SMD plastic package
- Excellent coplanarity and improved thermal behavior

#### **1.3 Applications**

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Reverse polarity protection

#### 1.4 Quick reference data

#### Table 1.Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
l <sub>F</sub>	forward current		-	-	200	mA
V <sub>R</sub>	reverse voltage		-	-	30	V
V <sub>F</sub> fo	forward voltage		[1]			
		$I_{F} = 0.1 \text{ mA}$	-	-	240	mV
		$I_F = 1 \text{ mA}$	-	-	320	mV
		I <sub>F</sub> = 10 mA	-	-	400	mV
		I <sub>F</sub> = 30 mA	-	-	500	mV
		I <sub>F</sub> = 100 mA	-	-	800	mV

 $\label{eq:point} \begin{tabular}{ll} \mbox{Pulse test: } t_p \leq 300 \ \mu \mbox{s; } \delta \leq 0.02. \end{tabular}$ 



# **BAT54CV**

#### Two Schottky barrier double diodes

# 2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)		
2	anode (diode 2)		
3	common cathode (diode 3, 4)		
4	anode (diode 3)	0	
5	anode (diode 4)		
6	common cathode (diode 1, 2)	1 2 3	1 2 3
			sym05

3. Ordering information

Table 3. Ord	Table 3. Ordering information			
Type number	Package			
	Name	Description	Version	
BAT54CV	-	plastic surface-mounted package; 6 leads	SOT666	

## 4. Marking

Table 4.         Marking codes	
Type number	Marking code
BAT54CV	C5

## 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V <sub>R</sub>	reverse voltage		-	30	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq$ 10 ms; $\delta \leq$ 0.5	-	0.85	A
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; t <sub>p</sub> = 8.3 ms	<u>[1]</u> -	2	А

# BAT54CV

#### Two Schottky barrier double diodes

Symbol	Parameter	Conditions	Min	Max	Unit
Per device	e, one diode loaded				
P <sub>tot</sub>	total power dissipation	total power dissipation $T_{amb} \le 25 \ ^{\circ}C$	[2]		
			[3]	350	mW
			<u>[4]</u> _	420	mW
Tj	junction temperature		-	125	°C
T <sub>amb</sub>	ambient temperature		-65	+125	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

Table 5. Limiting values ... continued

[1]  $T_j = 25 \,^{\circ}C$  prior to surge.

[2] Reflow soldering is the only recommended soldering method.

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard [3] footprint.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

#### **Thermal characteristics** 6.

Table 6.	Thermal characteristics	;				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device	e, one diode loaded					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1][2]</u>			
			[3] _	-	360	K/W
			[4] _	-	300	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		<u>[5]</u> _	-	175	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses  $P_R$  are a significant part of the total power losses.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

Soldering point of cathode tab. [5]

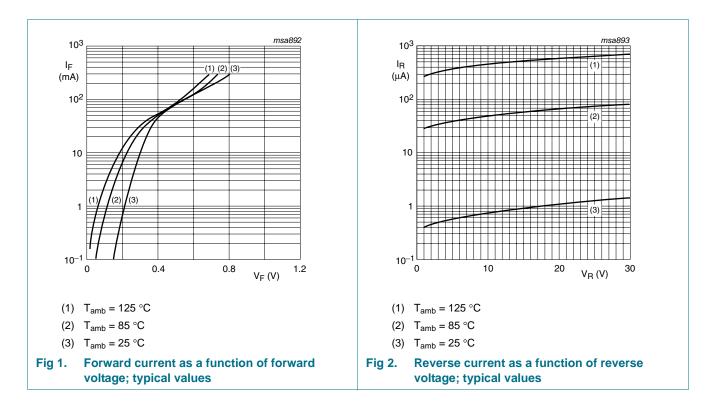
BAT54CV

Two Schottky barrier double diodes

# 7. Characteristics

<b>Table 7.</b> T <sub>amb</sub> = 25	Characteristics C unless otherwise s	pecified.				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	e					
V <sub>F</sub>	forward voltage		<u>[1]</u>			
		I <sub>F</sub> = 0.1 mA	-	-	240	mV
		I <sub>F</sub> = 1 mA	-	-	320	mV
		I <sub>F</sub> = 10 mA	-	-	400	mV
		I <sub>F</sub> = 30 mA	-	-	500	mV
		I <sub>F</sub> = 100 mA	-	-	800	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25 V	-	-	2	μΑ
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz	-	-	10	pF

 $\label{eq:point} \begin{tabular}{ll} \end{tabular} \begin{tabular}{ll} \end{tabular} 1 \end{tabular} \end{tabular} \begin{tabular}{ll} \end{tabular} \end{tabular} \begin{tabular}{ll} \end{tabular} \end{tabular} \end{tabular} \begin{tabular}{ll} \end{tabular} \end{ta$ 

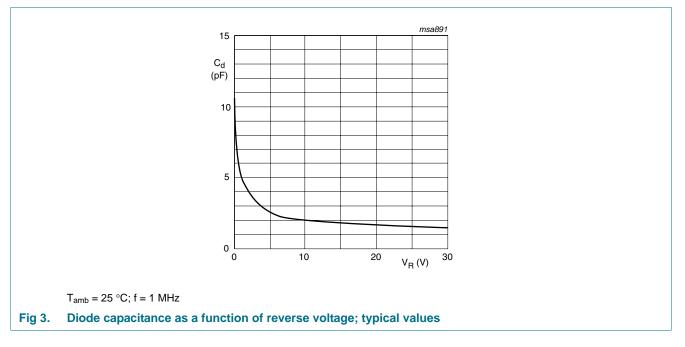


4 of 10

#### **NXP Semiconductors**

# BAT54CV

#### Two Schottky barrier double diodes

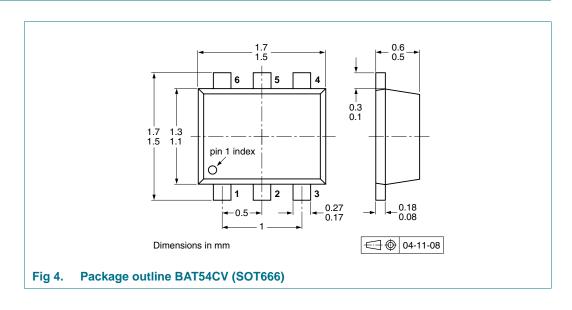


## 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



BAT54CV

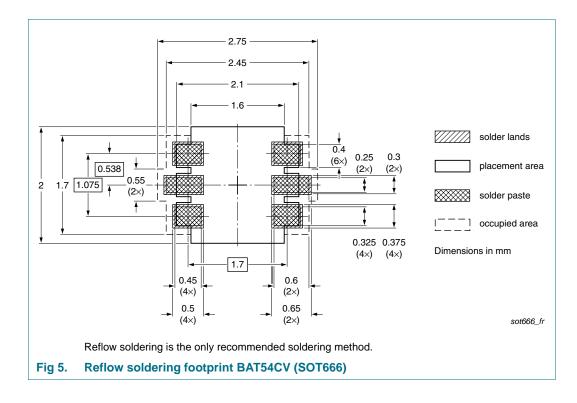
5 of 10

# **10. Packing information**

	<b>ing methods</b> x are the last t	hree digits of the 12NC ordering code.[1]	
Type number	Package	Description	Packing quantity
			4000
BAT54CV	SOT666	4 mm pitch, 8 mm tape and reel	-115

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

# 11. Soldering



6 of 10

#### Two Schottky barrier double diodes

# 12. Revision history

Table 9. Revision	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BAT54CV v.3	20101115	Product data sheet	-	BAT54CV_2
Modifications:	Section 1.2 '	Features and benefits": am	ended.	
	Table 1 "Qui	ck reference data": updated	ł.	
	Table 5 "Lim	iting values": P <sub>tot</sub> amended		
	• Table 6 "The	rmal characteristics": Rth(j-a	<sub>i)</sub> amended, R <sub>th(j-sp)</sub> ad	ded.
	<ul> <li>Figure 4: sup</li> </ul>	perseded by minimized out	ine drawing.	
	<ul> <li>Section 8 "Te</li> </ul>	est information": added.		
	Section 11 "S	Soldering": added.		
	Section 13 "	Legal information": updated	I.	
BAT54CV_2	20100115	Objective data sheet	-	BAT54CV_1
BAT54CV_1	20040922	Objective data sheet	-	-

# 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

#### 13.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

BAT54CV

#### Two Schottky barrier double diodes

Notice: All referenced brands, product names, service names and trademarks

13.4 Trademarks

are the property of their respective owners.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

# 14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

# **BAT54CV**

#### Two Schottky barrier double diodes

# **15. Contents**

1	Product profile 1
1.1	General description 1
1.2	Features and benefits 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 2
6	Thermal characteristics 3
7	Characteristics 4
8	Test information 5
8.1	Quality information 5
9	Package outline 5
10	Packing information 6
11	Soldering 6
12	Revision history 7
13	Legal information 8
13.1	Data sheet status 8
13.2	Definitions 8
13.3	Disclaimers 8
13.4	Trademarks 9
14	Contact information 9
15	Contents 10

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

#### © NXP B.V. 2010.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 15 November 2010 Document identifier: BAT54CV

# **AMEYA360** Components Supply Platform

# Authorized Distribution Brand :



# Website :

Welcome to visit www.ameya360.com

# Contact Us :

# > Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

# > Sales :

- Direct +86 (21) 6401-6692
- Email amall@ameya360.com
- QQ 800077892
- Skype ameyasales1 ameyasales2

# **Customer Service** :

Email service@ameya360.com

# > Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com